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# TIP31A / TIP31C NPN Epitaxial Silicon Transistor

#### **Features**

- Medium Power Linear Switching Applications
- Complementary to TIP32 Series



1.Base 2.Collector 3.Emitter

### **Ordering Information**

| Part Number | Top Mark | Package                  | Packing Method |
|-------------|----------|--------------------------|----------------|
| TIP31A      | TIP31A   | TO-220 3L (Single Gauge) | Bulk           |
| TIP31C      | TIP31C   | TO-220 3L (Single Gauge) | Bulk           |
| TIP31CTU    | TIP31C   | TO-220 3L (Single Gauge) | Rail           |

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_C = 25^{\circ}C$  unless otherwise noted.

| Symbol           | Parameter                 |        | Value      | Unit |  |
|------------------|---------------------------|--------|------------|------|--|
| V <sub>CBO</sub> | Collector Page Voltage    | TIP31A | 60         | - V  |  |
|                  | Collector-Base Voltage    | TIP31C | 100        |      |  |
| V <sub>CEO</sub> | Collector-Emitter Voltage | TIP31A | 60         | V    |  |
|                  | Collector-Emitter voltage | TIP31C | 100        |      |  |
| V <sub>EBO</sub> | Emitter-Base Voltage      |        | 5          | V    |  |
| I <sub>C</sub>   | Collector Current (DC)    |        | 3          | Α    |  |
| I <sub>CP</sub>  | Collector Current (Pulse) |        | 5          | Α    |  |
| I <sub>B</sub>   | Base Current              |        | 1          | Α    |  |
| $T_J$            | Junction Temperature      |        | 150        | °C   |  |
| T <sub>STG</sub> | Storage Temperature Range |        | -65 to 150 | °C   |  |

## **Thermal Characteristics**

Values are at  $T_C = 25^{\circ}C$  unless otherwise noted.

| Symbol         | Parameter                                     | Value | Unit |
|----------------|---|-------|------|
| P <sub>C</sub> | Collector Dissipation (T <sub>A</sub> = 25°C) | 2     | W    |
|                | Collector Dissipation (T <sub>C</sub> = 25°C) | 40    | ] vv |

## **Electrical Characteristics**

Values are at  $T_C = 25$ °C unless otherwise noted.

| Symbol                 | Parameter   |        | Conditions  | Min. | Max. | Unit |
|------------------------|---|--------|---|------|------|------|
| V <sub>CEO</sub> (sus) | Collector-Emitter Sustaining Voltage <sup>(1)</sup> | TIP31A | $I_C = 30 \text{ mA}, I_B = 0$                                | 60   |      | V    |
|                        |   | TIP31C |   | 100  |      |      |
| I <sub>CEO</sub>       | Collector Cut-Off Current                           | TIP31A | $V_{CE} = 30 \text{ V}, I_{B} = 0$                            |      | 0.3  | mA   |
|                        |   | TIP31C | $V_{CE} = 60 \text{ V}, I_{B} = 0$                            |      | 0.3  |      |
| I <sub>CES</sub>       | Collector Cut-Off Current                           | TIP31A | $V_{CE} = 60 \text{ V}, V_{EB} = 0$                           |      | 200  | μА   |
|                        |   | TIP31C | V <sub>CE</sub> = 100 V, V <sub>EB</sub> = 0                  |      | 200  |      |
| I <sub>EBO</sub>       | Emitter Cut-Off Current                             |        | $V_{EB} = 5 \text{ V}, I_{C} = 0$                             |      | 1    | mA   |
| h <sub>FE</sub>        | DC Current Gain <sup>(1)</sup>                      |        | $V_{CE} = 4 \text{ V}, I_{C} = 1 \text{ A}$                   | 25   |      |      |
|                        |   |        | $V_{CE} = 4 \text{ V}, I_{C} = 3 \text{ A}$                   | 10   | 50   |      |
| V <sub>CE</sub> (sat)  | Collector-Emitter Saturation Voltage <sup>(1)</sup> |        | $I_C = 3 \text{ A}, I_B = 375 \text{ mA}$                     |      | 1.2  | V    |
| V <sub>BE</sub> (on)   | Base-Emitter On Voltage <sup>(1)</sup>              |        | $V_{CE} = 4 \text{ V}, I_{C} = 3 \text{ A}$                   |      | 1.8  | V    |
| f <sub>T</sub>         | Current Gain Bandwidth Product                      |        | V <sub>CE</sub> = 10 V, I <sub>C</sub> = 500 mA,<br>f = 1 MHz | 3.0  |      | MHz  |

#### Note:

1. Pulse test: pw  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%.

# **Typical Performance Characteristics**

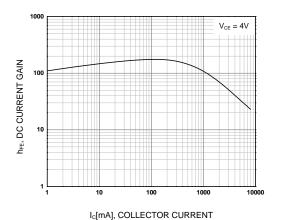


Figure 1. DC Current Gain

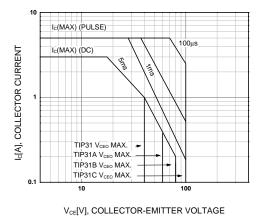
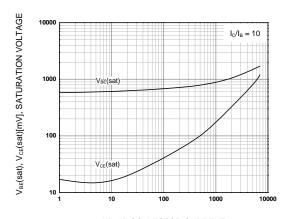


Figure 3. Safe Operating Area



I<sub>C</sub>[mA], COLLECTOR CURRENT

Figure 2. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

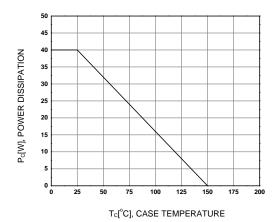
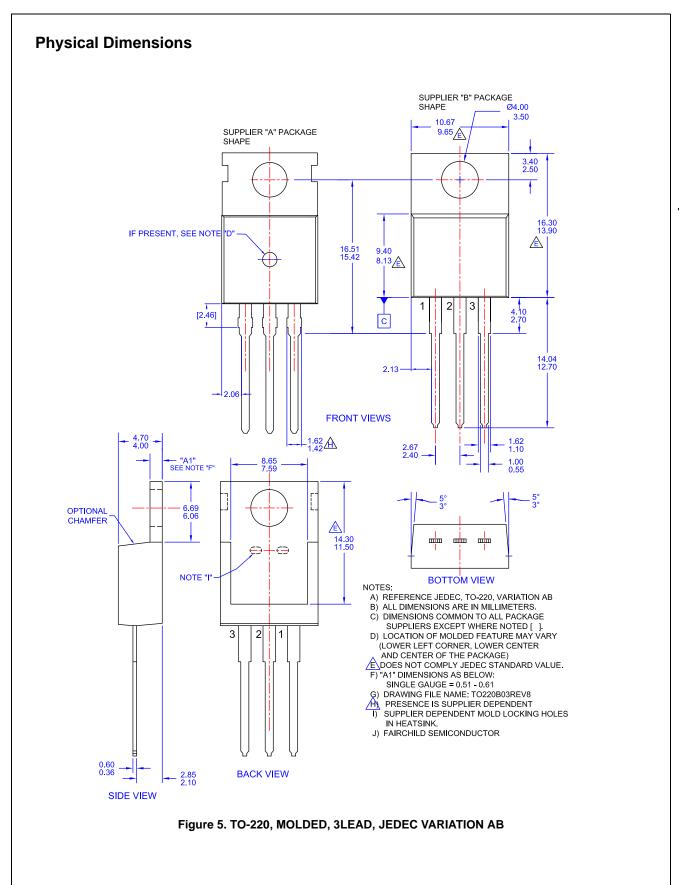


Figure 4. Power Derating



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